Accession Number

12324944

Author

Dochev D. Desmaris V. Meledin D. Pavolotsky A. Belitsky V.

Author Unabbreviated

Dochev Dimitar; Desmaris Vincent; Meledin Denis; Pavolotsky Alexey; Belitsky Victor Author/Editor Affiliation

Dochev D. Desmaris V. Meledin D. Pavolotsky A. Belitsky V. : Department of Earth and Space Sciences, Chalmers University of Technology, Gothenburg SE-412 96, Sweden Title

A Technology Demonstrator for 1.6-2.0 THz Waveguide HEB Receiver with a Novel Mixer Layout

Source

Journal of Infrared, Millimeter and Terahertz Waves, vol.32, no.4, April 2011, 451-65. Publisher: Springer US, USA.

Abstract

In this paper, we present our studies on a technology demonstrator for a balanced waveguide hot-electron bolometer (HEB) mixer operating in the 1.6-2.0 THz band. The design employs a novel layout for the HEB mixer combining several key technologies: all-metal THz waveguide micromachining, ultra-thin NbN film deposition and a micromachining of a silicon-on-insulator (SOI) substrate to manufacture the HEB mixer. In this paper, we present a novel mixer layout that greatly facilitates handling and mounting of the mixer chip via self-aligning as well as provides easy electrical interfacing. In our opinion, this opens up a real prospective for building multi-pixel waveguide THz receivers. Such receivers could be of interest for SOFIA, possible follow up of the Herschel HIFI, and even for ground based telescopes yet over limited periods of time with extremely dry weather (PWV less than 0.1 mm). (37 References).

708